### V10D120C-M3, V10D120CHM3

Vishay General Semiconductor

RoHS COMPLIANT

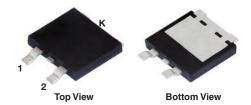
**HALOGEN** 

FREE

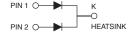
# **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.53 \text{ V}$  at  $I_F = 2.5 \text{ A}$ 

### TMBS® eSMP® Series TO-263AC (SMPD)



#### V10D120C



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5.0 A				
$V_{RRM}$	120 V				
I <sub>FSM</sub>	100 A				
$V_F$ at $I_F = 5.0$ A $(T_A = 125  ^{\circ}C)$	0.64 V				
T <sub>J</sub> max.	150 °C				
Package	TO-263AC (SMPD)				
Diode variations	Dual common cathode				

#### **FEATURES**

- Trench MOS Schottky technology
- · Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, inductrial, and automotive application.

#### **MECHANICAL DATA**

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER  Maximum repetitive peak reverse voltage		SYMBOL	V10D120C	UNIT	
		V <sub>RRM</sub>	120	V	
Maximum average forward rectified current (fig. 1)	per device		10	^	
	per diode	I <sub>F(AV)</sub>	5	A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	100	А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	

# V10D120C-M3, V10D120CHM3

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	——— T <sub>^</sub> = 25 °C I	V <sub>F</sub> <sup>(1)</sup>	0.61	-	V	
	I <sub>F</sub> = 5 A			0.79	0.94		
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.53	-		
	I <sub>F</sub> = 5 A			0.64	0.72		
Reverse current at rated V <sub>R</sub> per diode	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	- I <sub>R</sub> <sup>(2)</sup>	2.3	-	μΑ	
		T <sub>A</sub> = 125 °C		2.3	-	mA	
	V <sub>R</sub> = 120 V	T <sub>A</sub> = 25 °C		-	500	μΑ	
		T <sub>A</sub> = 125 °C		5	15	mA	

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	V10D120C	UNIT
	per diode	- R <sub>θJC</sub>	3.5	°C/W
Typical thermal resistance	per device		2.5	
	per device	R <sub>0</sub> JA (1)(2)	48	

#### **Notes**

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

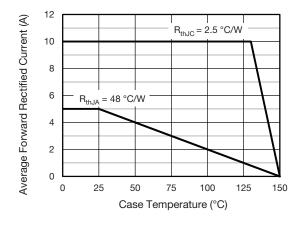
(2) Free air, without heatsink

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AC (SMPD)	V10D120C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel	
TO-263AC (SMPD)	V10D120CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel	

#### Note

(1) AEC-Q101 qualified

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)





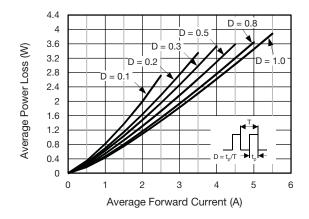


Fig. 2 - Forward Power Loss Characteristics Per Diode



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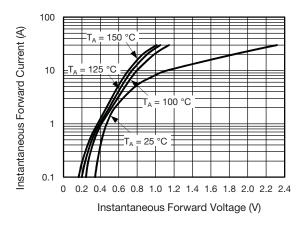


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

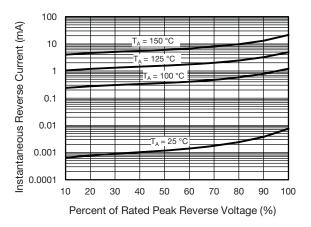


Fig. 4 - Typical Reverse Characteristics Per Diode

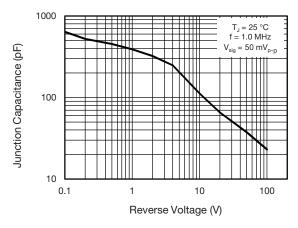


Fig. 5 - Typical Junction Capacitance Per Diode

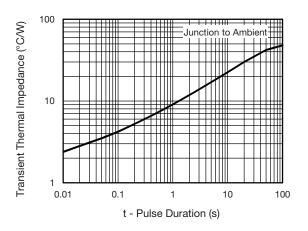


Fig. 6 - Typical Transient Thermal Impedance Per Device

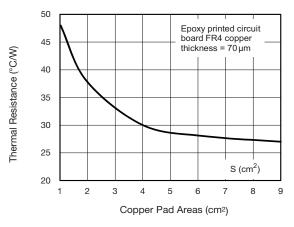
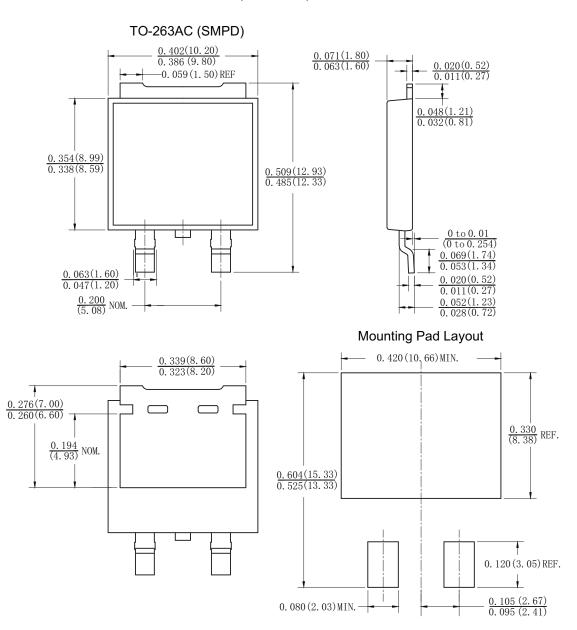


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas



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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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